

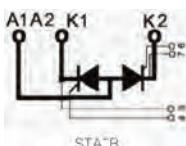
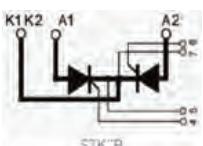
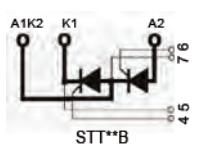
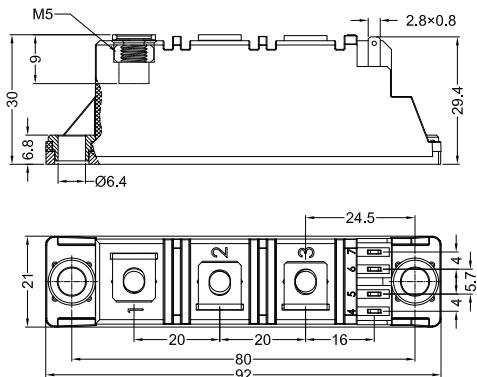
STT27GKxxB

Thyristor-Thyristor Modules



Type	V_{RSM} V_{DSM} V	V_{RSM} V_{DRM} V
STT27GK08B	900	800
STT27GK12B	1300	1200
STT27GK14B	1500	1400
STT27GK16B	1700	1600
STT27GK18B	1900	1800

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit
I_{TRMS} , I_{FRMS} I_{TAVM} , I_{FAVM}	$T_{VJ}=T_{VJM}$ $T_c=85^\circ C$; 180° sine	50 27	A
I_{TSM} , I_{FSM}	$T_{VJ}=45^\circ C$ $V_R=0$	520 560	A
	$T_{VJ}=T_{VJM}$ $V_R=0$	460 500	
$\int i^2 dt$	$T_{VJ}=45^\circ C$ $V_R=0$	1350 1300	$A^2 s$
	$T_{VJ}=T_{VJM}$ $V_R=0$	1050 1030	
$(di/dt)_{cr}$	$T_{VJ}=T_{VJM}$ $f=50Hz$, $t_p=200\mu s$ $V_D=2/3V_{DRM}$ $I_G=0.45A$	150	A/us
	non repetitive, $I_T=I_{TAVM}$ $dI/dt=0.45A/\mu s$	500	
$(dv/dt)_{cr}$	$T_{VJ}=T_{VJM}$; $V_{DRM}=2/3V_{DRM}$ $R_{GK}=\infty$; method 1 (linear voltage rise)	1000	V/us
P_{GM}	$T_{VJ}=T_{VJM}$ $I_T=I_{TAVM}$	10 5	W
P_{GAV}		0.5	W
V_{RGM}		10	V
T_{VJ} T_{VJM} T_{stg}		-40...+125 125 -40...+125	°C
V_{ISOL}	50/60Hz, RMS $I_{ISOL}\leq 1mA$	3000 3600	V~
M_d	Mounting torque (M5) Terminal connection torque (M5)	2.5-4.0/22-35 2.5-4.0/22-35	Nm/lb.in.
Weight	Typ.	110	g

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Symbol	Test Conditions	Characteristic Values	Unit
I_{RRM}, I_{DRM}	$T_{VJ}=T_{VJM}$; $V_R=V_{RRM}$; $V_D=V_{DRM}$	3	mA
V_T, V_F	$I_T, I_F=80A$; $T_{VJ}=25^\circ C$	1.64	V
V_{TO}	For power-loss calculations only ($T_{VJ}=125^\circ C$)	0.85	V
r_T		11	$m\Omega$
V_{GT}	$V_D=6V$; $T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	1.5 1.6	V
I_{GT}	$V_D=6V$; $T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	100 200	mA
V_{GD}	$T_{VJ}=T_{VJM}$; $V_D=2/3V_{DRM}$	0.2	V
I_{GD}		10	mA
I_L	$T_{VJ}=25^\circ C$; $t_p=10\mu s$; $V_D=6V$ $I_G=0.45A$; $dI/dt=0.45A/\mu s$	450	mA
I_H	$T_{VJ}=25^\circ C$; $V_D=6V$; $R_{GK}=\infty$	200	mA
t_{gd}	$T_{VJ}=25^\circ C$; $V_D=1/2V_{DRM}$ $I_G=0.45A$; $dI/dt=0.45A/\mu s$	2	us
t_q	$T_{VJ}=T_{VJM}$; $I_T=20A$; $t_p=200\mu s$; $-di/dt=10A/\mu s$ $V_R=100V$; $dv/dt=20V/\mu s$; $V_D=2/3V_{DRM}$	typ. 150	us
Q_s	$T_{VJ}=T_{VJM}$; $I_T, I_F=27A$; $-di/dt=0.64A/\mu s$	50	uC
I_{RM}		6	A
R_{thJC}	per thyristor/diode; DC current per module	0.88 0.44	K/W
R_{thJK}	per thyristor/diode; DC current per module	1.08 0.54	K/W
ds	Creeping distance on surface	12.7	mm
da	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s^2

FEATURES

- * International standard package
- * Copper base plate
- * Glass passivated chips
- * Isolation voltage 3600 V~
- * UL file NO.310749
- * RoHs compliant

APPLICATIONS

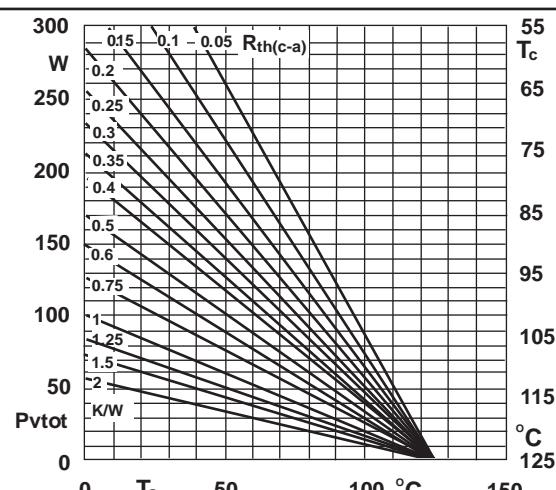
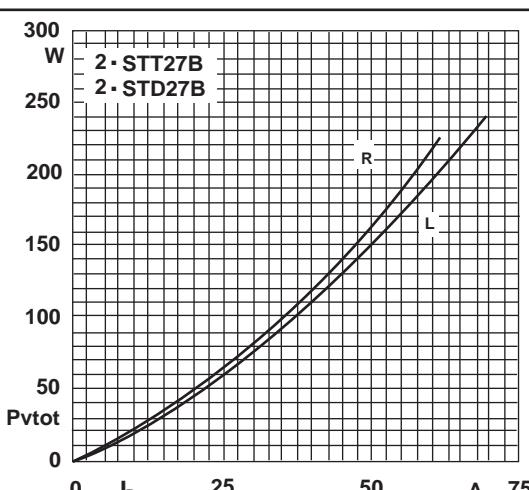
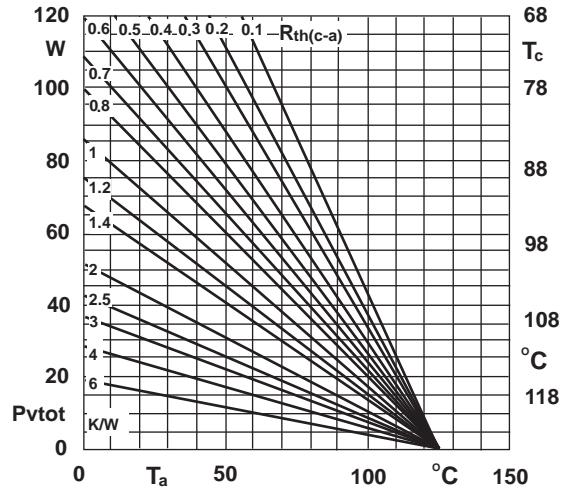
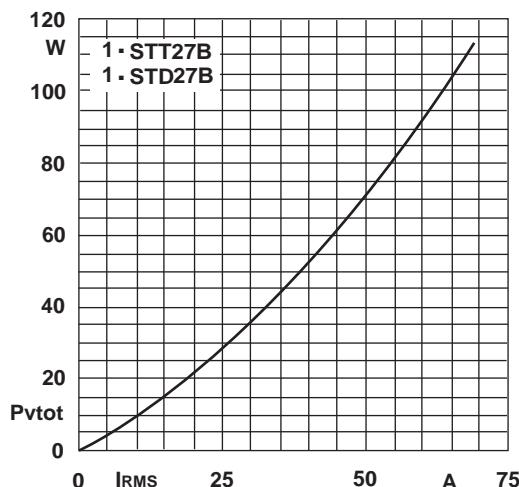
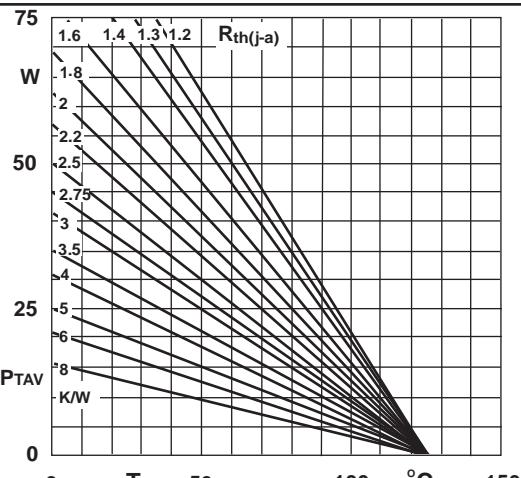
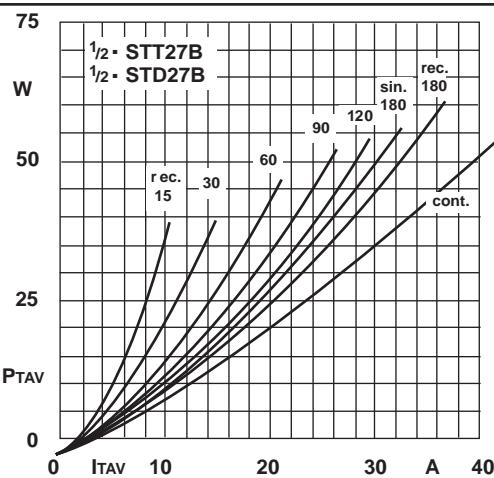
- * DC motor control
- * Softstart AC motor controller
- * Light, heat and temperature control

ADVANTAGES

- * Space and weight savings
- * Simple mounting with two screws
- * Improved temperature and power cycling
- * Reduced protection circuits

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